

# राष्ट्रीय प्रौद्योगिकी संस्थान सिलचर National Institute of Technology Silchar

(राष्ट्रीय महत्व का संस्थान)

#### (An Institute of National Importance)

www.nits.ac.in, Phone: 03842-242914, Fax: 03842-224797, Assam-788010 (INDIA)

Date: 08-01-2020

Advertisement No.: NITS/Dean(R&C)/ECE/541 /01/ 2020

Applications are invited from Indian citizens for a temporary of post of <u>**Project Assistant**</u> for the <u>CSIR</u> sponsored project in the Department of Electronics & Communication Engineering NIT Silchar.

Title of the project	High Pressure Phase Transitions, Electronic, Elastic and Optical			
	Properties of Selected Defect Chalcopyrite Semiconductors for			
	photodetector Application			
Sponsored Agency	Council of Scientific and Industrial Research (CSIR)			
Project sanction number	CSIR Project no. 70(0076)/19/EMR-II			
No. of posts	01			
Duration	3 years or co-terminus with the duration of the project.			
Principal Investigator (P.I)	Dr. Susanta Kumar Tripathy			

General Information and Terms & Conditions

	A T	
1.	Age Limit	Not more than 30 years
2.	Essential Qualification	M.Sc. with minimum of 60% marks or equivalent grade with
		Physics and Mathematics or equivalent degree.
		Desirable:
		M.Sc. in Electronics/Physics/ Material Science with minimum
		of 60% marks.
		NET/GATE qualified candidates may be given preference
3.	Desirable Experience	Expertise in the area of Electronic Materials
4.	Salary	Rs.12,000/- per month (consolidated)
		No other allowances are admissible
5.	Relaxation on qualification and	SC/ST/OBC/WOMEN/PWD candidates will get
	age	relaxation as per Govt of India Rules.
6.	Last date of receiving/submission	31st January 2020
	of filled up application form	•
7.	Reporting	Applicants are requested to submit their filled-up applications along
		with C.V. to the P.I. accompanying photocopies of all documents.
		Applicants are also requested to send the soft copy of the duly filled
		application along with C.V. & all necessary documents to the P.I
		through email. Dr. S. K. Tripathy, PI, Department of ECE, NIT
		Silchar, Assam-788010, Email: <a href="mailto:susantnits@gmail.com">susantnits@gmail.com</a>
8.	Date of interview, time, and	05 Feb 2020 at 11.00 AM, at the Deptt. fo ECE, NIT
	venue	Silchar, Assam-788010, India
9.	No objection certificate	Employed candidates are to submit no objection certificate
		from his / her employer at the time of interview.
10.	Institute right	The Institute has the discretion to restrict the number of
		candidates to be called for the interview on the basis of
		screening. No candidate may be recruited if suitable candidates
		are not found.
11.	Signing of the agreement	Selected candidates shall have to sign an agreement at the time
		of joining.

### National Institute of Technology Silchar

#### FORMAT of APPLICATION

## for **Project Assistant**

Paste recent passport size colored photograph

1.	Advertisement no	dated:				
2.	Title of the Project-					
3.	Department:					
4.	Name of the applicant	(in block letters):				
<b>5</b>	Eather's /Husband's N	amai				
Э.	Father's/Husband's N	ame.				
6.	Date of Birth (DD-MM-YYYY):					
7.	Age as on 31-01-2020:					
8.	Postal Address:					
	E-mail:	Phone no.:				
9.	Permanent Address:					
10.	Nationality:					
11.	. Marital Status:					
12.	Whether belongs to SC	C/ST/PH/OBC: (If yes, attach certificate):				
13	Educational Qualificat	ion: (Starting from Class X)				

Exam. passed	Board/ University	Divi sion	% age of marks / CPI	Year of passing	Subjects

14. NET/GATE Examinations Passed	d:
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II. GATE	Γ	I. NE	
lid upto Subject Score Valid upto	Valid upto	Qualifying date	Subject
lid upto Subject Score Vali	Valid upto	Qualifying date	Subject

### 15. Details of employments:

S1. No.	Name of the Organization	Name of the post	Period	Scale of pay and present pay	Nature of duty

16. Any other relevant information that you may like to furnish:

#### Declaration

]	I declare	that the a	bove info	rmation a	are true a	and corre	ect to the	best of	f my
knowle	edge and	belief.							

Date:	
Place	Signature of the applicant